Confirmation No.6431

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

PONOMAREV

Examiner:

Whalen, D.

Serial No.:

10/596,422

Group Art Unit:

4176

Filed:

June 13, 2006

Docket No.:

NL031497

Title:

METHOD FOR FORMING A STRAINED SI-CHANNEL IN A MOSFET

STRUCTURE

AMENDMENT AND RESPONSE

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Customer No. 65913

Dear Sir:

In response to the non-final Office Action dated October 29, 2007, please reconsider the application in view of the following amendments and remarks.

A complete listing of the claims, to include any amendments presented therein, begins on page 2 of this paper.

Remarks/Arguments follow on page 5.

Authorization is provided to charge/credit Deposit Account 50-0996 (NXPS.392PA) any requisite fees/overages to enter this paper.